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View Online at https://aerobasegroup.com/nsn/5961-01-067-7296

#### Inclosure Material:

Glass

# Overall Length:

Between 0.293 inches and 0.357 inches

#### Terminal Length:

Between 1.000 inches and 1.625 inches

#### **Overall Diameter:**

Between 0.215 inches and 0.235 inches

#### **End Application:**

4wasp class lhd; 2m/ate microminiauture automatic test equipment; nimitz class cvn; ticonderoga class cg (47); oliver perry class ffg; tarawa class lha; emory s. Land class as; forrestal class cv; spruance class dd (963); arleigh burke class ddg

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### Do-13

**Mounting Method:** 

Terminal

#### **Features Provided:**

Hermetically sealed case

#### **Criticality Code Justification:**

Feat

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

158.0 breakdown voltage, dc

#### **Current Rating Per Characteristic:**

1.00 milliamperes forward current, average peak

#### **Power Rating Per Characteristic:**

1.0 watts small-signal input power, common-collector major

#### Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

## **Special Features:**

Weapon system essential; junction pattern arrangement: pn

# Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# Terminal Type And Quantity:

2 uninsulated wire lead

# **Specification Data:**

81349-mil-s-19500/500 government specification

# Shelf Life:

N/a

# Unit Of Measure:

- --
- Demilitarization:

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